MBR2045EMFS, NRVB2045EMFS

Switch-mode Power Rectifiers

These state-of-the-art devices have the following features:

Features

- Low Power Loss / High Efficiency
- New Package Provides Capability of Inspection and Probe After Board Mounting
- Guardring for Stress Protection
- Low Forward Voltage Drop
- 150°C Operating Junction Temperature
- Wettable Flacks Option Available
- NRV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free and Halide-Free Devices

Mechanical Characteristics:

- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94–0 @ 0.125 in.
- Lead Finish: 100% Matte Sn (Tin)
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Device Meets MSL 1 Requirements

Applications

- Excellent Alternative to DPAK in Space—Constrained Automotive Applications
- Output Rectification in Compact Portable Consumer Applications
- Freewheeling Diode used with Inductive Loads

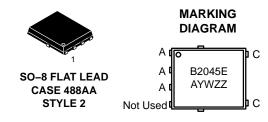


ON Semiconductor®

http://onsemi.com

SCHOTTKY BARRIER RECTIFIERS 20 AMPERES 45 VOLTS





B2045E = Specific Device Code A = Assembly Location

Y = Year
W = Work Week
ZZ = Lot Traceability

ORDERING INFORMATION

D	evice	Package	Shipping†
MBR204	5EMFST1G	SO-8 FL (Pb-Free)	1500 / Tape & Reel
MBR204	5EMFST3G	SO-8 FL (Pb-Free)	5000 / Tape & Reel
NRVB204	45EMFST1G	SO-8 FL (Pb-Free)	1500 / Tape & Reel
NRVB204	45EMFST3G	SO-8 FL (Pb-Free)	5000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	V _{RRM} V _{RWM}		V
DC Blocking Voltage	V_R	45	
Average Rectified Forward Current (Rated V_R , $T_C = 130$ °C)	I _{F(AV)}	20	А
Peak Repetitive Forward Current, (Rated V _R , Square Wave, 20 kHz, T _C = 120°C)	I _{FRM}	40	А
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	400	A
Storage Temperature Range	T _{stg}	-65 to +175	°C
Operating Junction Temperature	TJ	-55 to +150	°C
Unclamped Inductive Switching Energy (10 mH Inductor, Non-repetitive)	E _{AS}	150	mJ
ESD Rating (Human Body Model)		3B	
ESD Rating (Machine Model)		M4	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

NOTE: The heat generated must be less than the thermal conductivity from Junction-to-Ambient: dPD/dTJ < 1/RJA

THERMAL CHARACTERISTICS

Characteristic	Symbol	Тур	Max	Unit
Thermal Resistance, Junction-to-Case, Steady State (Assumes 600 mm² 1 oz. copper bond pad, on a FR4 board)	$R_{ heta JC}$	-	1.6	°C/W

ELECTRICAL CHARACTERISTICS

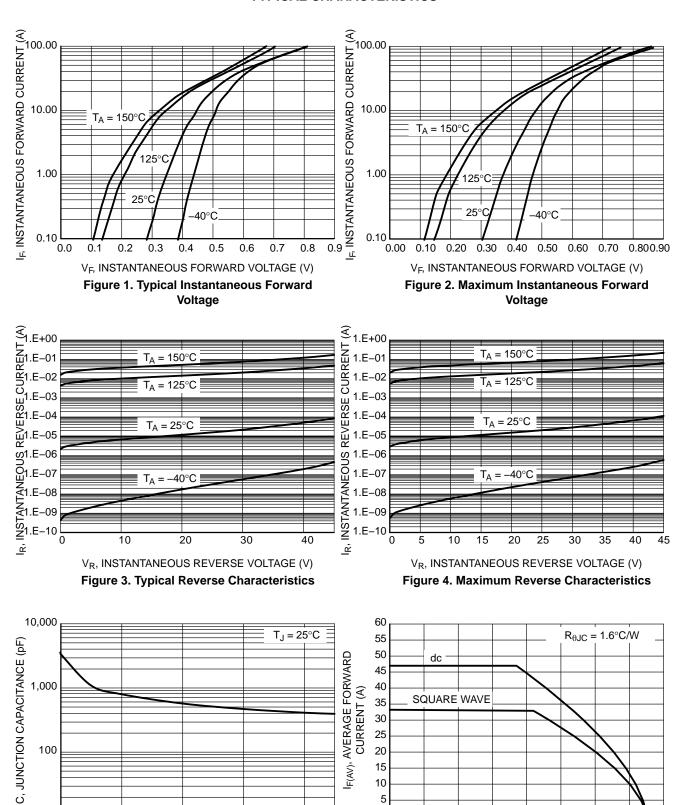
Instantaneous Forward Voltage (Note 1)	VF			V
$(i_F = 10 \text{ A}, T_J = 125^{\circ}\text{C})$		0.35	0.47	
$(i_F = 10 \text{ A}, T_J = 25^{\circ}\text{C})$		0.45	0.56	
$(i_F = 20 \text{ A}, T_J = 125^{\circ}\text{C})$		0.43	0.58	
$(i_F = 20 \text{ A}, T_J = 25^{\circ}\text{C})$		0.51	0.64	
Instantaneous Reverse Current (Note 1)	i _R			mA
(Rated dc Voltage, T _J = 125°C)		48	100	
(Rated dc Voltage, T _J = 25°C)		0.09	0.40	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

^{1.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

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TYPICAL CHARACTERISTICS



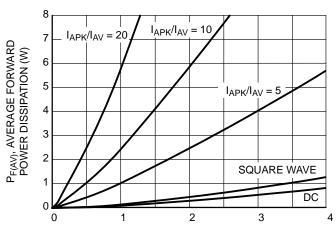
V_R, REVERSE VOLTAGE (V) **Figure 5. Typical Junction Capacitance**

T_C, CASE TEMPERATURE (°C) Figure 6. Current Derating

140 160

MBR2045EMFS, NRVB2045EMFS

TYPICAL CHARACTERISTICS



 $I_{F(AV)}$, AVERAGE FORWARD CURRENT (A)

Figure 7. Forward Power Dissipation

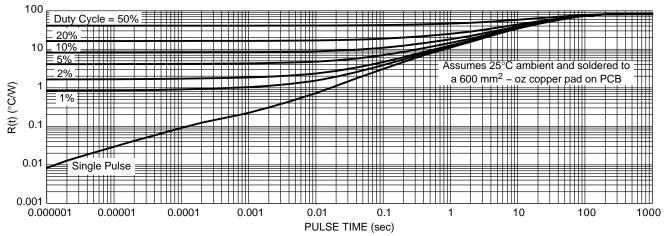


Figure 8. Thermal Response



0.10

0.10

SIDE VIEW

DFN5 5x6, 1.27P (SO-8FL) CASE 488AA ISSUE N

DATE 25 JUN 2018

NOTES:

- DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION D1 AND E1 DO NOT INCLUDE MOLD FLASH PROTRUSIONS OR GATE BURRS

	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	0.90	1.00	1.10	
A1	0.00		0.05	
b	0.33	0.41	0.51	
С	0.23	0.28	0.33	
D	5.00	5.15	5.30	
D1	4.70	4.90	5.10	
D2	3.80	4.00	4.20	
E	6.00	6.15	6.30	
E1	5.70	5.90	6.10	
E2	3.45	3.65	3.85	
е	1.27 BSC			
G	0.51	0.575	0.71	
K	1.20	1.35	1.50	
L	0.51	0.575	0.71	
L1	0.125 REF			
M	3.00	3.40	3.80	
θ	0 °		12 °	

GENERIC MARKING DIAGRAM*



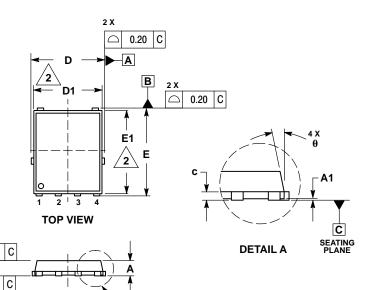
XXXXXX = Specific Device Code

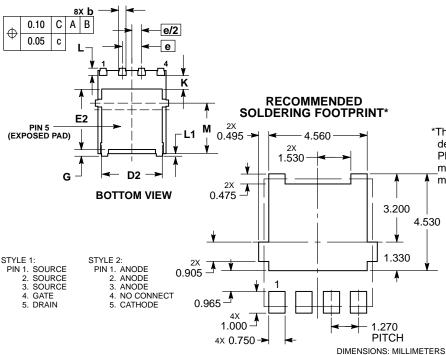
= Assembly Location Α

Υ = Year W = Work Week

ZZ = Lot Traceability

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present. Some products may not follow the Generic Marking.





DETAIL A

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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DESCRIPTION:	DFN5 5x6, 1.27P (SO-8FL)		PAGE 1 OF 1

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